

FEATURES

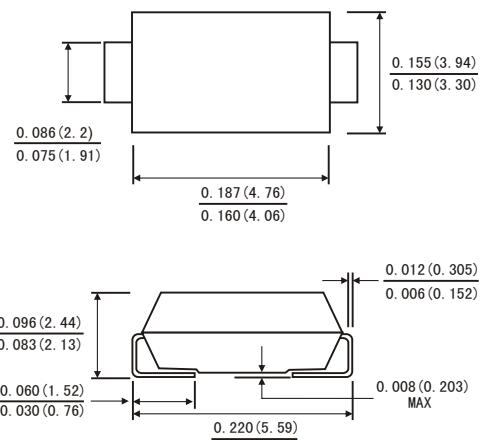
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Built-in strain relief
- For surface mounted applications
- Low profile package
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling , and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



MECHANICAL DATA

- Case: JEDEC SMB(DO-214AA) molded plastic body
- Terminals: solder plated ,solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Weight: 0.003ounce,0.093 gram

SMB(DO-214AA)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	V _{RRM}	SS 22	SS 23	SS 24	SS 25	SS 26	SS 28	SS 210	SS 215	SS 220	Volts															
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	Volts															
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	57	71	105	140	Volts															
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	Volts															
Maximum average forward rectified current (See Fig. 1)	I _(AV)	2.0									Amps															
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	50.0									Amps															
Maximum instantaneous forward voltage at 2.0 A(note 1)	V _F	0.55		0.75		0.85		0.90		0.95	Volts															
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	$T_A = 25^\circ C$ $T_A = 100^\circ C$	0.2																							
Typical thermal resistance (Note 2)	R _{JA} R _{JL}		10.0																							
Operating junction temperature range	T _J	-65 to+150																								
Storage temperature range	T _{TG}	-65 to+150																								

Notes: 1.Pulse test: 300 μ s pulse width,1% duty cycle

2. P.C.B. mounted with 0.2 X 0.2"(5.0 X 5.0mm)copper pad areas

RATINGS AND CHARACTERISTIC CURVES

FIG.1-FORWARD CURRENT DERATING CURVE

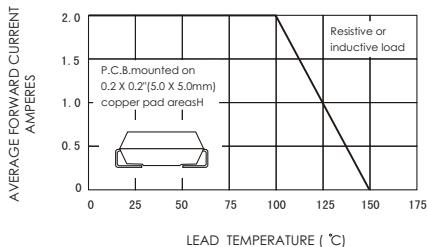


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

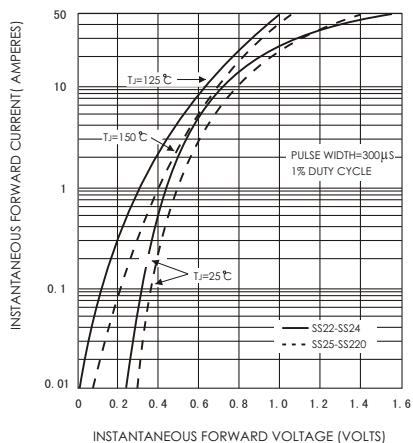


FIG.5-TYPICAL JUNCTION CAPACITANCE

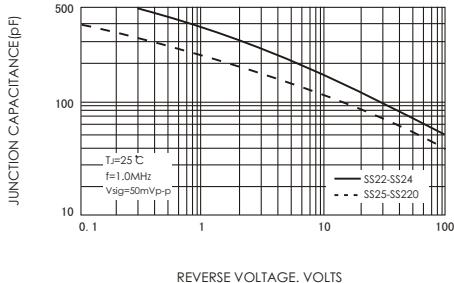


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

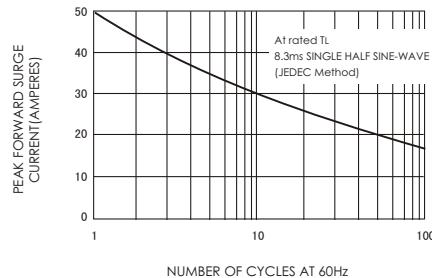


FIG.4-TYPICAL REVERSE CHARACTERISTICS

